Selection and jump rules in electronic R am an scattering from G aA s/A l_x G $a_1 x$ A s articial atom s

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A theoretical description of electronic R am an scattering from G aA s/A l_x G a₁ $_x$ A s arti cial atom s under the in uence of an external magnetic eld is presented. R am an spectra with laser excitation energy in the intervalE $_{gap}$ 30 m eV to E $_{gap}$ are computed in the polarized and depolarized geom etry. The polarization ratios for the collective and single-particle excitations indicate a breakdown of the R am an polarization selection rules once the magnetic eld is switched on. A R am an intensity jump rule at the band gap is predicted in our calculations. This rule can be a useful tool for identifying the physical nature (charge or spin) of the electronic excitations in quantum dots in low magnetic elds.

PACS num bers: 78.30 Fs, 78.67 Hc, 78.66 Fd Keywords: Quantum dots, spectroscopy, Ram an scattering, electronic excitations

The spectrum of electronic excitations of quantum dots is, in many cases, required as basic information for developing relevant applications. By performing inelastic light (Raman) scattering experiments, one can examine a whole sector of elementary excitations not accessible through photolum inescence or absorption measurements. In the 1990s, Raman experiments on GaAs/GaAlAs deep-etched quantum dots reported interesting results. An overview that summarizes this work can be found in Ref. [1].

Schuller et al.^{2,3} obtained Raman spectra dom inated by collective excitations by illum inating the sam ples with lasers whose energy values were well (40 m eV) above the e ective band-gap of the dot. Two types of collective m odes were found; the charge-density excitations (CDEs) and the spin-density excitations (SDEs) and these can be distinguished by polarization selection rules. CDEs are observed when the polarizations of the incident and scattered light are parallel to each other (polarized geom etry), while SDEs are detected in a con guration where the scattered light polarization is perpendicular to the incident one (depolarized geometry). These polarization selection rules are obtained in the fram ework of the o resonant approximation (ORA)⁴ where the Raman transition amplitude is directly determ ined by the multipole strength functions of the nalexcited states. The authors in R ef. [4] investigate the lim its to the general use of the ORA depending on the quantum numbers of the nalexcited states and the characteristic lateral con nement energy of the quantum dot. For a laser excitation energy, h i, below band-gap the o -resonant regime is only reached form onopolar and quadrupolarm odes when E _{gap} 30 m eV⁴. Strong R am an peaks, appearh i ing in both geom etries, when the energy of the incident light is quite close to the e ective band-gap (extrem e resonance regime), were interpreted by Lockwood et al.⁵ in terms of single-particle excitations (SPEs). More recently, Brocke et al.⁶ reported the rst observations of a few -electron CDEs in InG aAs self-assem bled quantum dots by means of Ram an spectroscopy.

In this paper, we compute the near-resonance R am an spectrum of a medium -size disk-shaped quantum dot containing 42 electrons in an external magnetic eld applied perpendicular to the plane of the dot. The method and approxim ations used to obtain them any-body wave functions and energies of the required states are explained in Ref. [7]. Energies and wave-functions of the nal excited states are obtained by means of the random phase approximation⁸ (RPA). The calculation of the monopole operator matrix elements between each nal state and the ground state, allows the identi cation of the collective modes (CDEs, SDEs) and the SPEs. By computing the Ram an polarization ratios we evaluate the extent to which the magnetic eld breaks down the polarization selection rules for both collective and SPEs. W e report the rst observation of what we term the Ram an intensity jum p-rule. This e ect, more clearly seen for the collective modes, can be enunciated as follows: a monotonic increase of a Raman peak intensity when the incident laser energy is increased from below up to the e ective band-gap of the dot in the polarized (depolarized) geom etry indicates that the excited state associated with that peak is a charge (spin) excitation. If we look at the sam e state in its opposite geometry, we nd quite sm all values of the Raman intensities at any incident energy except at the e ective band-gap, in which case a sudden jump of the Ram an intensity should be detected.

From theory⁹, we know that the Ram an peak intensity is proportional to the transition am plitude squared, $A_{fi}f$, where

$$A_{fi} = \frac{X}{\prod_{int} \frac{hf f_e^+ r jintihint f_e r jii}{h_i (E_{int} E_i) + i_{int}}}$$
(1)

For simplicity, the initial, intermediate and nal quantized states of the radiation eld are not written explicitly. jii, jinti and jfi are, respectively, the initial (ground), interm ediate and nal (excited) electronic states of the quantum dot. \hat{H}_{e} r is the electron-radiation interaction Hamiltonian⁴, and _{int} is a phenom enologicaldamping parameter. A consistent calculation of the R am an intensity requires reliable approxim ations to the many-particle wave functions ju, jinti, and jfi. Since we are considering incident laser energies (h i) of the order of the e ective band-gap of the quantum dot, as is the case form ost experim entalwork, interm ediate states with an additional electron in the conduction band and one hole in the valence band will be the relevant contributors to the sum m ation in Eq. (1). The m atrix elem ent hint \hat{H}_{e} r juir epresents the virtual transition from the N_e-electron ground state to an interm ediate state in which an incident photon is annihilated and an electronhole pair is created. The inverse mechanism is described by the matrix element hf $\mathbf{\hat{h}}_{e}^{+}$ r jinti, where the electronhole pair is annihilated and a scattered photon of energy $h_{f} < h_{i}$ is emitted.

W e modelled our GaAs quantum dot with a disk of thickness L = 25 nm. The electron motion in the growth direction is conned by a hard wall potential. On the other hand, the lateral conning potential is assumed to be parabolic with a characteristic energy $\sim !_0 = 12 \text{ meV}$. Hole states in the valence band are found by diagonalizing the Kohn-Luttinger Hamiltonian¹⁰ in the presence of an external connement and the 42 electron background.

W e focus on m onopolar excitations. This m eans that the total angular m om enta of the initial and nal states are equal. C ollective excitations (CDEs, SDEs) correspond to jf i states giving a signi cantly nonzero value of the m atrix element:

$$D_{fi}^{0} = f d^{0}, [e^{Y}, e^{-}, e^{Y}_{\#}, e^{+}]i; (2)$$

where d^0 ; is the matrix element of the monopole operator, de ned in Ref. [7]. The greek subindices denote the orbital part of the HF electronic states, while the spin projection is explicitly indicated by the arrow. The plus (minus) sign in Eq. (2) corresponds to the CDEs (SDEs).

Figure 1 displays the monopolar excitation spectrum of the modelled dot in an external magnetic eld. CDEs (open squares) and SDEs (open triangles), whose contribution to the energy-weighted sum nules (EW SRs)⁷ exceeds 5 %, are specially indicated. The contribution to the EW SR of each collective mode is shown by means of the size of the symbols. Charge (SPEs(C)) and spin (SPEs(S)) single-particle excitations are also represented with long and short horizontal bars, respectively. For the CDE mode, one notices two features: i) its energy evolves in a sm ooth way as B is increased, and ii) the square sizes do not change with the eld. This latter fact indicates the strong collective nature of the mode, which concentrates all of the oscillator-strength. Only at B = 5:5 T

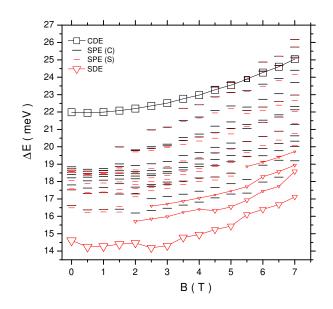


FIG.1: (Coloronline) Monopolar excitation spectrum of the dot.

are there two collective states sharing the whole contribution to the EW SR. The lowest excitation energies in Fig. 1 correspond to the SDEs. One can see at B = 2, 2:5, and 5:5 T starting points for new SDE bands. The lowest energy band shows no signi cant dependence on the magnetic eld up to B = 2 T, while at higher elds the SDEs follow a quasi-linear dependence. Notice how the oscillator-strength of the SDEs, concentrated in one state up to 1:5 T, is redistributed between more than one mode for higher values of B. SPEs are in between the SDEs and the CDE. They are grouped in compact bunches of states at low values of B . W hen B 3 T a m ore hom ogeneous distributions of these states is found. Notice that the rst single-particle excited state (spin or charge) is relatively isolated from the rest for any value of the magnetic eld.

The Ram an spectra we present in this paper are com puted in a backscattering con guration where the incident and scattering angles, de ned with respect to the norm alof the dot are xed at 20°. The incident laser energy is measured with respect to the e ective band-gap of the dot, $E_{gap} = E_{int}^{(0)} E_i$, where $E_{int}^{(0)}$ is the lowest interm ediate state energy, and E $_{\rm i}$ { the ground state energy. Each interm ediate state entering Eq. (1) satis es the condition $E_{int} = E_{int}^0$ $\sim!_{LO}$,with $\sim!_{LO}$ 30 m eV being the threshhold excitation energy for the spontaneous em ission of longitudinal optical phonons in G aAs. In this interval, the phenom enological parameter, int, related to the lifetime of the jinti states, is xed at 0.5 m eV. For higher excitation energies, the em ission of LO phonons becom es active and the widths of those states

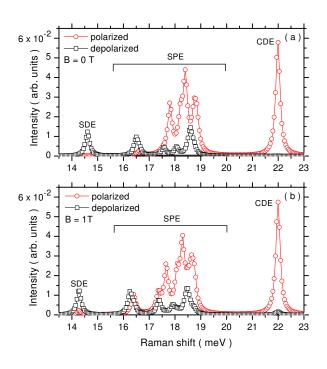


FIG. 2: (Color online) Polarized and depolarized R am an spectra at B = 0 and 1 T. The incident laser energy is $h_i = E_{gap}$ 2.5 meV.

should experience a sudden increase¹¹. This regime is not considered in the present paper. Calculated monopolar R am an spectra in both geom etries at B = 0 and 1 T are shown in Fig. 2. The energy of the incident laser is 2:5 m eV below the band gap. The Ram an peaks related to the SDE, SPEs and CDE are explicitly indicated. Figure 2 (a) reveals an SDE peak which is only visible in the depolarized geometry. The situation for the CDE peak is completely the opposite; a non-zero R am an intensity is only observed in the polarized geometry. However, once the magnetic eld is switched on this polarization selection rule is partially broken. As can be seen in Fig. 2(b), non-trivial values of the Ram an intensities associated with the CDE and SDE are obtained in both geom etries, although the polarized (depolarized) geometry remains the favorable con guration for detecting the CDE (SDE).

The polarization ratio r of a R am an peak related to a charge (collective or single-particle) excitation is dened by the fraction whose numerator is the squared R am an amplitude computed in the depolarized geometry, which is the unfavorable geometry for this mode, and the denom inator is the squared amplitude in the polarized geometry. For spin excitations the fraction is inverted. At B = 0, the polarization ratios of the CDE and SDE are $r_{CDE}^{B=0T}$ = 3:6 10 4 and $r_{SDE}^{B=0T}$ = 2:0 10 7 . In a magnetic eld of 1 T, the ratios reach the values $r_{CDE}^{B=1T}$ = 2:8 10 2 and $r_{SDE}^{B=1T}$ = 1:7 10 1 . Notice the

strong perturbing e ects of the external magnetic eld on the Ram an polarization selection rules, especially for the SDE.

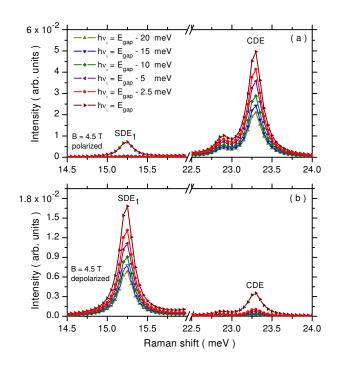


FIG.3: (Color online) The collective R am an peaks at B = 4.5 T as h $_{\rm i}$ approaches the band gap.

SPEs with excitation energies ranging from 16 to 19 m eV are apparent in Fig. 2. At B = 0 and 1 T, the SPEs(C) and SPEs(S) are quite close in energy and the overlapping intensities make a separate qualitative experim entalanalysis di cult. How ever, we can com pute r for each SPE.AtB = 0, the squared am plitudes of SPEs(C) in the depolarized geom etry are, on average, three orders ofm agnitude sm aller than in the polarized geom etry, giving an average polarization ratio $hr_{\text{SPE}(C)}^{\text{B}=0T}$ i = 3.0 10 ³. This indicates that monopolar Ram an peaks related to SPE (C) obey, by analogy with the CDEs, a polarization selection rule at $B = 0 T \cdot At B = 1 T$, however, the Ram an amplitudes exhibit comparable magnitudes in both geom etries, giving an average polarization ratio, $hr_{SPE(C)}^{B=1T}i = 0.26$. For the SPEs(S), a transition from $hr_{\text{SPE}(S)}^{\text{B}=0T}i=2:1$ 10 ⁴ to $hr_{\text{SPE}(S)}^{\text{B}=1T}i=1:1$ is found.

The jump rule is depicted in Fig. 3. We focus on the behavior of the R am an peaks linked to the collective modes. SDE_1 labels the low est spin excitation. Fig. 3(a) illustrates how the polarized R am an intensities change when the energy of the incident laser is increased from $h_i = E_{gap}$ 30 meV up to E_{gap} . A monotonic increase of the R am an intensity related to the CDE is apparent. However, for the SDE we nd quite sm all values of the R am an intensities except at the band-gap, where

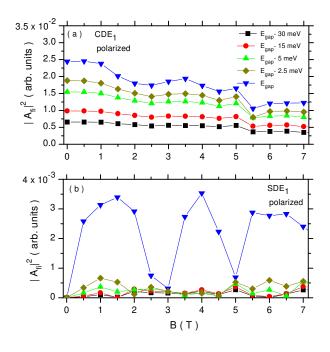


FIG.4: (Color online) Squared R am an am plitudes related to the (a) CDE and (b) SDE_1 in the polarized geometry versus the external magnetic eld.

a sudden jump in the intensity is observed. Fig. 3(b) shows results in the depolarized geometry, the Ram an peak that experiences a monotonic increase is the SDE_1 , while a jump rule is observed for the CDE. The jump rule involves two factors: the character (charge or spin) of the electronic excitation associated with a given Ram an peak, and the polarization in which the Ram an intensity is computed (or measured).

It is useful to exam ine the validity of the jump rule at di erent magnetic eld values. Fig. 4 show sthe variation of the Ram an intensities of the CDE and SDE₁ with the magnetic eld in the polarized geometry. Results are shown for several values of the incident light energy. A monotonic dependence of the CDE Ram an intensity is observed. For the SDE₁, a jump rule picture is obtained at any eld value except at B = 2.5, 3:0 and 5:0 T. Notice at B = 0 T that the conventional polarization selection rules are full led independently of the incident laser energy.

In Fig. 5, we present a similar analysis for the R am an intensities associated with the SPE (C)₁ and SPE (S)₁. From an experimental point of view, the R am an peaks related to these single-particle excited states, which are relatively isolated from the others, can in principle, be followed as a function of the magnetic eld. Notice in Fig. 5 (a) that the R am an intensities vary strongly when them agnetic eld is changed, and them onotonic increase as a function of the laser energy. On the other hand, for the SPE (S)₁, we not two magnetic eld intervals where

a jum p rule picture applies.

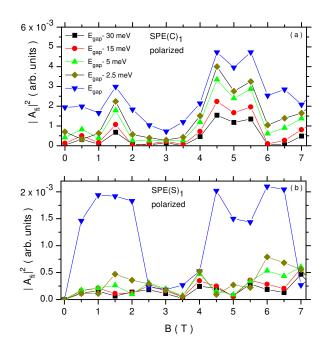


FIG.5: (Color online) The same as Fig. 4, but for the (a) SPE (C)₁ and (b) SPE (S)₁ peaks.

The Ram an intensity jump rule results from the breakdown of the polarization selection rules at the band gap excitation, where the ORA is no longer valid. We have exam ined this interesting e ect as a function of the external magnetic eld for all monopolar modes. For low values of B ranging from 0:5 to 2:0 T the rule is always obeyed for all the excitations and it would be very interesting to test it experimentally. For certain limited 2:5 T the jump rule collapses as shown values of B for example in Fig. 4 and Fig. 5. How ever the magnetic eld values where this happens can vary depending on the particular mode. The reason why the Raman intensity jum p rule collapses at speci c values of the m agnetic eld is related to changes in the properties of the quantum dot electronic ground and excited states that are manifested in small values of the Raman matrix elements in association with cancellation e ects in Eq. (1). Doubtlessly this point deserves further theoretical and experim ental analysis. The Ram an intensity jum p rule is not universal with respect to the external magnetic eld at higher eld values but it can be a useful tool for identifying the spin or charge nature of the electronic excitations in quantum dots.

Part of this work was perform ed at the Institute for M icrostructural Sciences (\mathbb{M} S), N ational R escarch C ouncil, O ttawa. A D. acknow ledges the hospitality and support of \mathbb{M} S.

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